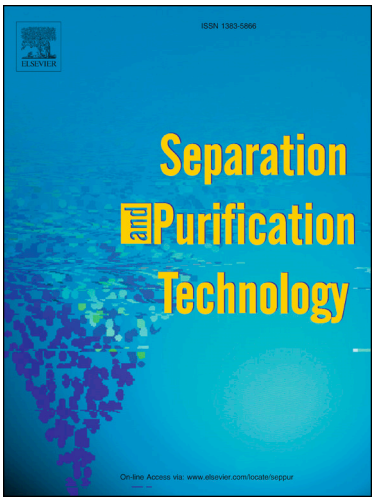

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A nanosheet-like α-Bi_2O_3/g-C_3N_4 heterostructure modified by plasmonic metallic Bi and oxygen vacancies with high photodegradation activity of organic pollutants

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Abstract

Bi/α-Bi_2O_3 nanoparticles rich in oxygen vacancies in the surface and subsurface loading on g-C_3N_4 nanosheets were realized via a calcination-photoreduction technique，during which the emergence of oxygen vacancies and the generation of metallic Bi from α-Bi_2O_3 decomposition were achieved simultaneously. The co-occurrence of Bi nanoparticles and oxygen vacancies was favorable for the

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